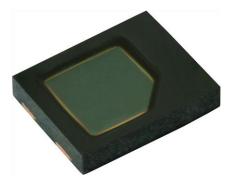
# VEMD5010X01

**Vishay Semiconductors** 



## **Silicon PIN Photodiode**



### DESCRIPTION

VEMD5010X01 is a high speed and high sensitive PIN photodiode. It is a low profile surface mount device (SMD) including the chip with a 7.5 mm<sup>2</sup> sensitive area detecting visible and near infrared radiation.

### **FEATURES**

- Package type: surface mount
- Package form: top view
- Dimensions (L x W x H in mm): 5 x 4 x 0.9
- Radiant sensitive area (in mm<sup>2</sup>): 7.5
- AEC-Q101 qualified
- High photo sensitivity
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity:  $\phi = \pm 65^{\circ}$
- Floor life: 72 h, MSL 4, according to J-STD-020
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **APPLICATIONS**

• High speed photo detector

PRODUCT SUMMARY				
COMPONENT	I <sub>ra</sub> (μA)	φ (deg)	λ <sub>0.1</sub> (nm)	
VEMD5010X01	48	± 65	430 to 1100	

#### Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VEMD5010X01	Tape and reel	MOQ: 1000 pcs, 1000 pcs/reel	Top view		
VEMD5010X01-GS15	Tape and reel	MOQ: 5000 pcs, 5000 pcs/reel	Top view		

#### Note

• MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	20	V	
Power dissipation	T <sub>amb</sub> ≤ 25 °C	Pv	215	mW	
Junction temperature		Тj	110	°C	
Operating temperature range		T <sub>amb</sub>	-40 to +110	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +110	°C	
Soldering temperature	Acc. reflow solder profile fig. 8	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient		R <sub>thJA</sub>	350	K/W	
ESD safety HBM	$\pm$ 2000 V, 1.5 kΩ, 100 pF, 3 pulses	ESD <sub>HBM</sub>	≥2	kV	



HALOGEN FREE GREEN (5-2008)

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# VEMD5010X01



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<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 50 mA	V <sub>F</sub>		1	1.3	V
Breakdown voltage	I <sub>R</sub> = 100 μA, E = 0	V <sub>(BR)</sub>	20			V
Reverse dark current	V <sub>R</sub> = 10 V, E = 0	I <sub>ro</sub>		2	30	nA
Diode capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	CD		70		pF
	V <sub>R</sub> = 3 V, f = 1 MHz, E = 0	CD		25	40	pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	Vo		350		mV
Temperature coefficient of Vo	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	TK <sub>Vo</sub>		-2.6		mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	l <sub>k</sub>		45		μA
Temperature coefficient of $I_k$	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	TK <sub>lk</sub>		0.1		%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_R = 5 \text{ V}$	I <sub>ra</sub>	40	48		μA
Angle of half sensitivity		φ		± 65		deg
Wavelength of peak sensitivity		λ <sub>p</sub>		940		nm
Range of spectral bandwidth		λ <sub>0.1</sub>		430 to 1100		nm
Noise equivalent power	$V_{R}$ = 10 V, $\lambda$ = 950 nm	NEP		4 x 10 <sup>-14</sup>		W/√Hz
Rise time	$V_R$ = 10 V, $R_L$ = 1 k $\Omega$ , $\lambda$ = 820 nm	t <sub>r</sub>		100		ns
Fall time	$V_R$ = 10 V, $R_L$ = 1 k $\Omega$ , $\lambda$ = 820 nm	t <sub>f</sub>		100		ns

### BASIC CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

Basic characteristics graphs to be extended to 110 °C ambient temperatures where applicable.

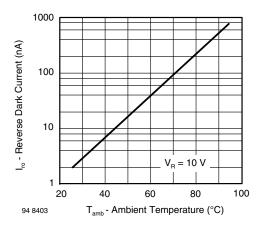


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

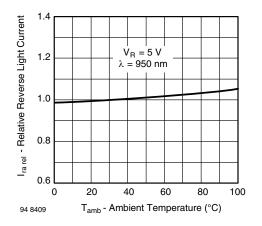
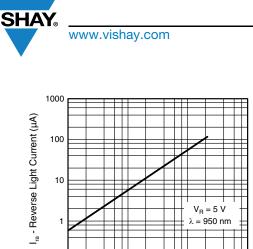


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature



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0.01 0.1 1 12787 E<sub>e</sub> - Irradiance (mW/cm<sup>2</sup>)

10

0

Fig. 3 - Reverse Light Current vs. Irradiance

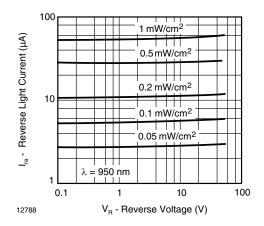


Fig. 4 - Reverse Light Current vs. Reverse Voltage

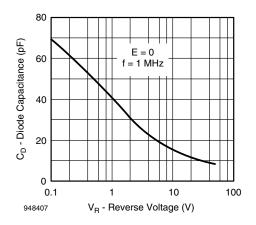


Fig. 5 - Diode Capacitance vs. Reverse Voltage

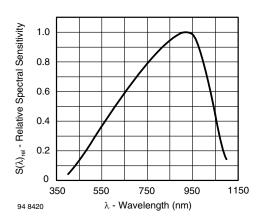


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

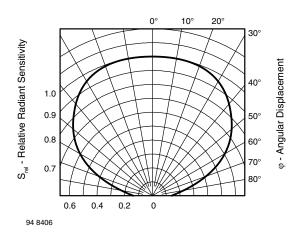


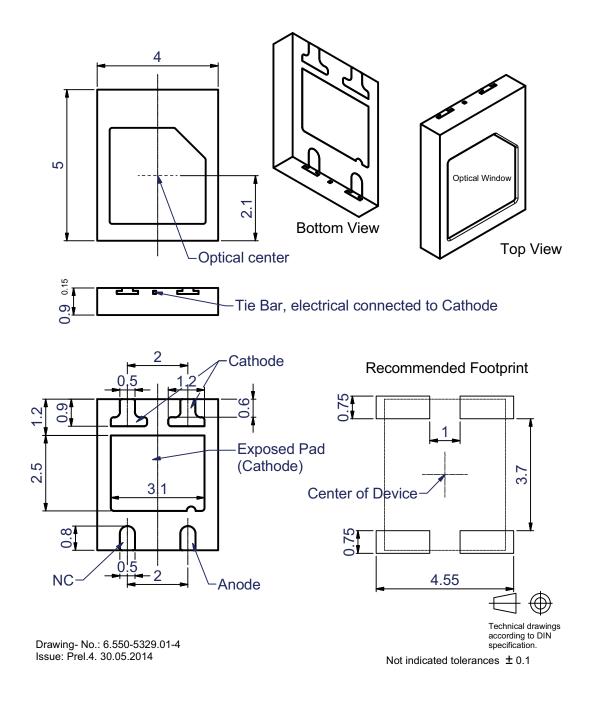
Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement





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### **PACKAGE DIMENSIONS** in millimeters

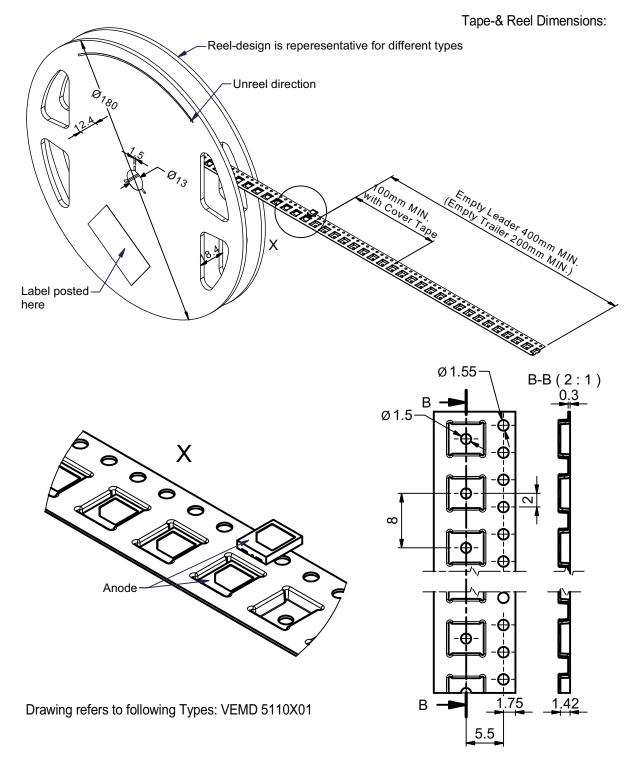




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### TAPE AND REEL DIMENSIONS in millimeters

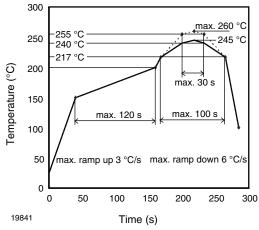


Drawing-No.: 9.800-5129.01-4; Issue: Prel. 14.04.2014

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### SOLDER PROFILE



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Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020D

### DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

### FLOOR LIFE

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020: Moisture sensitivity: Level 4 Floor life: 72 h Conditions:  $T_{amb} < 30$  °C, RH < 60 %

### DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or recommended conditions:

192 h at 40 °C (+ 5 °C), RH < 5 % or 96 h at 60 °C (+ 5 °C), RH < 5 %.



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